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c) The text of the second edition was

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combined with that of IEC 60747-7-5. This publication is to be read in conjunction with IEC 60747-1:2006. This publication is to be read in conjunction with IEC 60747-1:2006.

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b) Clauses 3, 4, 5 and 7 were amended with some deletions of information no longer in use or already included in other parts of the IEC 60747 series, and with some necessary additions; c) Clause 6 was moved and added to Clause 7 of this third edition; d) some parts of Clause 7 were moved and added to Clause 7

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b) "Clause 4 Terminology and letter symbols" was divided into "Clause 3 Terms and definitions" and "Clause 4 Letter symbols" was amended with additions and deletions. c) Clause 5, 6 and 7 were amended with necessary additions and deletions. This publication is to be read in conjunction with IEC 60747-1:2006.

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